Measurements of Recombination of Electrons with H_3^+ and H_5^+ lons*

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The electron-ion recombination coefficients for H_3^* and H_5^* ions have been determined by means of a microwave afterglow/mass-spectrometer apparatus. Measurements of electron density decays in helium-hydrogen mixtures are correlated with the decay of mass-identified ion currents to the wall of the microwave cavity. At low partial pressures of hydrogen in the mixture, the ion H_3^* dominates the ion composition and the ion wall current "tracks" the electron density decay curves. From recombination controlled electron density decay curves, the values $\alpha(H_3^*)=(2.9\pm0.3)$, (2.3 ± 0.3) , and $(2.0\pm0.2)\times10^{-7}$ cm³/sec are obtained at 205, 300, and 450 K, respectively. At higher partial pressures of hydrogen and low temperatures, where H_5^* is the dominant ion, the value $\alpha(H_5^*)=(3.6\pm1.0)\times10^{-6}$ cm³/sec is obtained at 205 K. The implications of these results concerning ionization levels in the atmospheres of the outer planets and in the intersteller medium are discussed.

I. INTRODUCTION

Optical spectroscopy has been employed to detect molecular hydrogen as the principal neutral gas species in the atmospheres of Jupiter,¹ Saturn,² Uranus, and Neptune,³ and in interstellar clouds.⁴ The principal steps in the formation of hydrogen plasmas in the planetary ionospheres and in the interstellar medium are thought to be photoionization of H₂ by the processes

$$h\nu + H_2 - H_2^+ + e$$

- H⁺ + H + e (1)

followed by conversion of H_2^+ and H^+ ions to H_3^+ ions by the fast reactions^{5,6}

$$H_2^+ + H_2 \rightarrow H_3^+ + H$$
 (2)

and

$$H^{+} + H_2 + H_2 - H_3^{+} + H_2$$
. (3)

The reaction (3) may be not important in the interstellar medium.

Theoretical models of Jupiter's atmosphere⁷⁻⁹ and of interstellar clouds^{10,11} have been proposed in which the recombination of electrons with H_3^+ ions is the dominant loss process for these ions. In the absence of accurate measurements of their recombination coefficients, the models so far have adopted estimated values.

The rate of recombination of H_3^+ ions with electrons is expected to vary with the temperature of the ions and of the electrons. In the regions of interest, the neutral gas and ion temperatures vary from as low as ~4 K in the interstellar medium to ~150 K in the upper atmosphere of Jupiter. The electron temperature is thought to be greater than the ion temperature by as much as several hundred degrees in the atmospheres of the outer

planets.¹² Thus laboratory measurements should, if possible, cover an extensive range of ion and electron temperatures in order that the measured rates be applicable to all regions where electronion recombination of the ion H_3^+ is important.

The present experiment involves production of a plasma of H_3^+ (or H_5^+) ions and electrons in our microwave afterglow/mass-spectrometer apparatus and measurement of the rates of decay of electron density and of mass-identified ion wall currents under recombination controlled conditions. From the curves of the electron density decay we determine the rates of electron-ion recombination at various temperatures under conditions such that the electron and ion temperatures are equal to the gas temperature: $T_e = T_i = T_{gas}$.

II. APPARATUS AND METHOD OF MEASUREMENT

The apparatus and method of measurement used in the present studies has been described in detail a number of times 13-15 and will be discussed only briefly here. Figure 1 is a simplified diagram of our experimental apparatus. Research-grade hydrogen and ultrahigh-purity helium acting as a buffer gas are admitted to the microwave cavity by means of an ultrahigh-vacuum gas-handling system. A plasma containing hydrogen ions and electrons is generated by means of a microwave pulse lasting 40 μ sec from a magnetron operating at a repetition rate of 10 sec^{-1} . The resonantfrequency shifts $\Delta \omega(t)$ of the microwave cavity are determined by noting the time of maximum reflection of a low-energy probing signal of swept frequency. These measured frequency shifts are used to calculate the "microwave-averaged" electron density $\bar{n}_{\mu\nu}(t)$ defined by

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$$\vec{n}_{\mu w}(t) = \frac{\int_{\text{vol}} n_e(\vec{\mathbf{r}}, t) E_p^2(\vec{\mathbf{r}}) \, dV}{\int_{\text{vol}} E_p^2(\vec{\mathbf{r}}) \, dV} = C \left[1 + \left(\frac{\nu_{\text{eff}}}{\omega} \right)^2 \right] \Delta \omega(t) \,, \quad (4)$$

where $n_e(\mathbf{r}, t)$ is the electron density, $E_b(\mathbf{r})$ is the probing microwave electric field, C is a coefficient involving a group of physical constants, and ν_{eff} is the effective electron-helium collision frequency.¹⁵ The use of helium buffer gas at pressures approaching 20 Torr necessitates a ~3-5% correction of the electron densities¹⁵ determined from the frequency shifts compared to the low-pressure case, $\nu_{\rm eff} \ll \omega$.

A fraction of the ions which diffuse to the cavity wall and effuse through a small sampling hole enter a differentially pumped quadrupole mass spectrometer, where they are mass identified. The ions counts at each afterglow time interval are coherently summed over many cycles by means of a multichannel analyzer operating in a multiscaling mode. In this manner, the decays of the positive ion wall currents are determined during the afterglow.

Under experimental conditions where only one ion species (H_3^+) predominates in the afterglow and electron-ion recombination is the only significant afterglow process (i.e., electron attachment, diffusion, and production processes are negligible) the electron density continuity equation simplifies to

$$\frac{\partial n_e}{\partial t} \simeq -\alpha n_+ n_e \simeq -\alpha n_e^2, \qquad (5)$$

where α represents the two-body electron-ion recombination coefficient, and we have set $n_e \simeq n_+$ because of the near neutrality of the afterglow plasma. The solution of this equation yields the well-known "recombination decay" form

$$1/n_e(t) = 1/n_e(0) + \alpha t$$
, (6)

pulsed magnetron pulse (plasma generation) generator microwave resonant cavity electron mult. quadrupole u.h. vacuum gas-handling system mass spectrom. zeolite trap trig. klystron fast multi-channel pumps (∆ω(t)-n_e meas) analyzer

which indicates that the reciprocal of the electron density increases linearly with time, the slope of the curve yielding the recombination coefficient α .

In the cases of higher hydrogen pressures, however, two ions, H_3^+ and H_5^+ , are present and decay in an apparent chemical equilibrium with each other during the afterglow. It can be shown that the "recombination decay" form is still valid¹³ if α is replaced by an effective recombination coefficient $\alpha_{\rm eff}$ given by

$$\alpha_{\rm eff} = \frac{\alpha({\rm H}_{\rm 3}^{+}) + R\alpha({\rm H}_{\rm 5}^{+})}{1 + R}, \qquad (7)$$

where $\alpha(H_3^+)$ and $\alpha(H_5^+)$ are the recombination coefficients for H_3^+ and H_5^+ , respectively, and R is the ion concentration ratio $[H_5^+]/[H_3^+]$. By varying R by changing the hydrogen concentration the measured curve of α_{eff} vs R can be used to evaluate $\alpha(H_3^+)$ and $\alpha(H_5^+)$ [the intercept at R=0is $\alpha(H_3^+)$; the limiting value for large R is $\alpha(H_5^+)$].

The analysis of the measured recombination decay curves to obtain the recombination coefficients involves consideration of the effects of ambipolar diffusion on the spatial distribution of the electrons within the cavity. As discussed previously,¹⁵ tabulated correction factors¹⁶ are applied to the slopes of the $1/\overline{n}_{\mu w}$ -vs-t curves to obtain the values of the recombination coefficients.

III. RESULTS

A. H₃⁺ Data

At helium pressures of ~9-27 Torr and hydrogen pressures of ~5-13 mTorr the principal afterglow ion is H₃⁺. This ion is evidently formed by the sequence: Penning ionization of H, by helium metastables, followed by rapid conversion of H_2^+ to H_3^+ by reaction (2).

FIG. 1. Microwave afterglow apparatus employing differentially pumped quadrupole mass spectrometer to monitor the currents of various ions diffusing to the cavity walls (see text).



An example of the data obtained at T = 300 K is shown in Fig. 2. In Fig. 2(a) the experimental data follow a "recombination decay" (straight line) over a factor of 20 in electron density to a time of 10 msec, and then the curve turns upward owing to diffusion effects. In Fig. 2(b) the ion wall current curves are compared with the electron density decay curve. The dashed line through the H_3^+ curve is the $\bar{n}_{\mu w}$ curve renormalized. Although the H_3^+ curve does not "track" the electron density particularly well in the early afterglow, H_3^+ is the only important ion throughout. While the ion H_5^+ is present, the ratio of ion wall currents H_5^+/H_3^+ is approximately 10⁻³, so that the effect of the ion H_5^+ on the determination of $\alpha(H_3^+)$ is negligible. After correction for ambipolar diffusion effects, the slope of the straight line in Fig. 2(a) yields the value $\alpha(H_3^+) = 2.3 \times 10^{-7} \text{ cm}^3/\text{sec}$ at 300 K. The deduced values of $\alpha(H_3^+)$ vary by less than 5% as the helium pressure is varied between 14 and 27 Torr.

To study the H_3^+ recombination at T = 450 K, the microwave cavity was insulated and heated. An example of the data obtained at this temperature is shown in Fig. 3. Figure 3(a) is the recombination plot; the data follow a straight line over a factor of 14 in electron density and then depart upward owing to diffusion. In Fig. 3(b) the only ion species observed, H_3^+ , is seen to more or less track the electron density curve. The corrected slope of

the straight line in the plot of $1/\bar{n}_{\mu w}$ vs t yields the value $\alpha(H_3^+) = 2.0 \times 10^{-7} \text{ cm}^3/\text{sec}$ at 450 K. The deduced values vary by less than 5% as the helium pressure is varied from 17 to 20 Torr and the hydrogen pressure varied from 5.5 to 7.5 mTorr.

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To study $\alpha(H_3^+)$ at T = 205 K, the cavity was immersed in a dry-ice bath and the temperature measured by a copper-constantan thermocouple. The rate of formation of the ion H_5^+ showed a great increase at T = 205 K in comparison to the measurements at T = 300 K and T = 450 K. In Fig. 4(b) are plotted the H_3^+ and H_5^+ ion wall currents and the relative electron density values. The dashed lines through the H_3^+ and H_5^+ ion curves are the electron density curves renormalized, indicating the "tracking" condition. In Fig. 4(a) the electron density data follow a recombination decay over a factor of 25 in electron density. indicating that the plasma is recombination controlled. The corrected slope of the straight line yields the effective recombination coefficient $\alpha_{\rm eff} = 3.26 \times 10^{-7} \, {\rm cm}^3/{\rm sec}$. After correcting for the presence of the ion H_5^+ by using $\alpha(H_5^+)$ $=3.6 \times 10^{-6} \text{ cm}^3/\text{sec}$ at T = 205 K (see the next subsection), the recombination coefficient $\alpha(H_3^+)$ $=2.9\times10^{-7}$ cm³/sec is obtained at 205 K. As at the higher temperatures, the values of $\alpha(H_3^+)$ vary little (<4%) as the helium pressure is varied from 8.6 to 16.6 Torr and the hydrogen pressure varied from 8 to 13 mTorr.



FIG. 2: (a) "Recombination plot" of electron density decay at 300 K. (b) Comparison of H_3^+ ion wall current and electron density decays.



FIG. 3. (a) "Recombination plot" of electron density decay at 450 K. (b) Comparison of H_3^+ ion wall current and electron density decays.



 $H_3^+ + H_2 + He \rightarrow H_5^+ + He$. (8)

By increasing the partial pressure of hydrogen, the ion composition is shifted from the dominance of H_3^+ to that of H_5^+ , presumably as a result of the increasing importance of the conversion reaction As may be seen in Fig. 5(b), the ion wall currents of H_5^+ and H_3^+ are observed to decay together, maintaining a constant ratio throughout most of the afterglow. Unfortunately, the tracking between ion wall currents and the electron density decay curve



FIG. 4. (a) "Recombination plot" of electron density decay under effective recombination coefficient conditions at 205 K (see text). (b) Comparison of electron density and ion wall current decays under conditions where the ions H_3^+ and H_5^+ decay in apparent equilibrium. The dashed lines through the H_3^+ and H_5^+ data are scaled values of the electron density normalized to the curves at 2 msec.



afterglow time (msec)

FIG. 5. (a) "Recombination plot" of electron density decay under effective recombination coefficient conditions at 205 K (see text). (b) Comparison of electron density and ion wall current decays under conditions where the ions H_5^+ and H_3^+ decay in apparent equilibrium and a small amount of the ion 29⁺ is noted. The dashed line through the H_5^+ data are scaled values of the electron density normalized to the curve at 2 msec.

is not very good. Furthermore, there is a small concentration of the impurity ion 29⁺ present. It may be either the ion HN_2^+ or the ion HCO^+ because nitrogen and carbon monoxide are the major impurities in the helium buffer gas. From Fig. 5(a) the corrected slope of the curve yields an effective recombination coefficient $\alpha_{eff} = 2.3 \times 10^{-6}$ cm³/sec. Values of α_{eff} were obtained as a function of the H_5^+ and H_3^+ ion wall current ratio over the range 10^{-2} -8.2 by varying the hydrogen concentration from 10^{-2} to 0.6 Torr. The observed $\alpha_{\rm eff}$ values are shown by the crosses in Fig. 6. In order to compare the observed and predicted variations of $\alpha_{\rm eff}$, we have assumed that the measured ion wall current ratio is equal to the ion concentration ratio $[H_5^+]/[H_3^+]$. The solid curve represents the variation of α_{eff} with R predicted by Eq. (7). The values which give this degree of fit at T = 205 K are $\alpha(H_5^+) = 3.6 \times 10^{-6}$ cm³/sec and $\alpha({\rm H_3^+}) = 2.9 \times 10^{-7} {\rm \ cm^3/sec.}$

IV. DISCUSSION AND CONCLUSIONS

The uncertainties in the determinations of $\alpha(H_3^+)$ and $\alpha(H_5^+)$ are estimated in the following manner. Systematic errors in the resonant-frequency measurements of the microwave cavity are less than 1%. The error in the afterglow time measurement (determined from a crystal oscilla-



FIG. 6. Effective recombination coefficient α_{eff} for different $[H_5^+] / [H_3^+]$ wall current ratios (measured at 2 msec in the afterglow). The solid line is a fit of the data to Eq. (7).

tor time-mark generator) is also less than 1%. The error in the electron density determinations due to collision-frequency corrections of the frequency-shift data is negligible. The principal errors in the determinations of $\alpha(H_3^+)$ and $\alpha(H_5^+)$ result from uncertainties in the diffusion correction factors.¹⁶ These uncertainties arise from imperfect knowledge of the initial spatial distribution of the electrons in the cavity and of the values of the ambipolar diffusion coefficients. This may lead to a $\sim 5\%$ error. Combining these uncertainties with that arising from the presence of the minority ion, the recombination coefficients of the ion H_{3}^{+} are found to be (2.9 ± 0.3) , (2.3 ± 0.3) , and $(2.0 \pm 0.2) \times 10^{-7}$ cm³/sec at 205, 300, and 450 K, respectively.

The ion 29⁺, presumably HCO⁺, which has a recombination coefficient of 3.3×10^{-7} cm³/sec at 205 K,¹⁷ or N₂H⁺ (with an estimated recombination coefficient of $\sim 3 \times 10^{-7}$ cm³/sec), prevents us from reaching the asymptotic value at large *R* in our $\alpha(H_5^+)$ measurements. It appears that a 5–10% uncertainty may arise from this source. Considering the uncertainty in the determination of the ion wall current ratio $R = [H_5^+]/[H_3^+]$ and the presence of the impurity ion 29⁺, we expect a larger uncertainty in the H₅⁺-recombination determination and assign the value $\alpha(H_5^+) = (3.6 \pm 1.0) \times 10^{-6}$ cm³/sec at 205 K.

The dependence of $\alpha(\mathrm{H_3}^+)$ on temperature is shown in Fig. 7. The dashed line represents a $T^{-1/2}$ temperature dependence, which is a reasonable fit to the data. The theory of the direct dissociative recombination process¹⁸ suggests that the recombination rate for simple ions in a fixed distribution of vibrational states should vary with the electron temperature as

$$\alpha(T_e) = c T_e^{-1/2} \,. \tag{9}$$

Our results indicate that this temperature dependence is obeyed, even though gas heating $(T_e = T_i = T_{gas})$ rather than selective heating of electrons $(T_e > T_i = T_{gas})$ was used. At these low temperatures (≤ 450 K), where the ions probably are predominantly in the ground vibrational state, the two types of temperature variation should lead to the same variation in recombination coefficient.

Several experiments had been performed to determine the electron loss in hydrogen. In 1949, Biondi and Brown¹⁹ used the microwave cavity method without mass-spectrometric analysis to determine the electron density decays in hydrogen. They found an electron-ion recombination coefficient of 2.5×10^{-6} cm³/sec at 300 K, independent of the pressure between 3 and 12 Torr. At such high hydrogen pressures it is likely that the principal afterglow ion was H₅⁺, so that the measured



FIG. 7. Electron-ion recombination coefficient for H_3^+ at T = 205, 300, and 450 K.

value probably refers to $\alpha({\rm H_5}^+)$ and is in agreement with a reasonable extrapolation of the present results to 300 K.

Varnerin,²⁰ using a microwave absorption afterglow technique, again without mass analysis, reported his determinations of recombination coefficients in hydrogen. They varied from a value of 3×10^{-7} cm³/sec at hydrogen pressures of 1-3 Torr to a value of 2.5×10^{-6} cm³/sec at pressures of 30-50 Torr. He paid more attention to purity, diffusing his hydrogen through hot palladium and baking his discharge tube thoroughly to outgas it. The pressure dependence of the recombination coefficient observed by Varnerin may reflect the changing concentrations of H_3^+ and H_5^+ as the principal afterglow ions as the pressure is changed. His value of 3×10^{-7} cm³/sec at low pressures is about 30% higher than the present results for $\alpha(H_3^+)$ at T = 300 K, while at high pressures his value of 2.5×10^{-6} cm³/sec is also in reasonable agreement with an extrapolation of our $\alpha(H_5^+)$ value to 300 K.

Persson and Brown²¹ used intense microwave discharges in a microwave afterglow study of hydrogen and found that higher-mode ambipolar diffusion loss accounted fully for the observed electron concentration decays. The electron-ion recombination coefficient in these studies was inferred to be less than 3×10^{-8} cm³/sec. The measured ambipolar diffusion coefficient yielded a reduced ion mobility $\mu_0 = 16.6$ cm²/V sec, which is in excellent agreement with the measured mobility of mass-identified H⁺ ions.²² Thus, in these studies H⁺ was evidently the ion produced by the intense discharge and may have been the principal afterglow ion [although we do not understand why significant conversion of H⁺ to H₃⁺ via reaction (3) did not occur on the time scale of their afterglow measurements]. With the atomic ion H^+ , significant recombination loss is excluded, and their results are compatible with the other studies.

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One may compare our results with measured values¹⁸ of electron-ion recombination coefficients for ions such as N_2^+ , O_2^+ , NO^+ , $N_2^+ \cdot N_2$, $O_2^{\diamond +} \cdot O_2$, and $NO^+ \cdot NO$. The recombination coefficient for H_3^+ (~10⁻⁷ cm³/sec) is comparable in magnitude to that for $\alpha(N_2^+)$, $\alpha(O_2^+)$, and $\alpha(NO^+)$, while the coefficient for $H_5^+ = (H_3^+ \cdot H_2)$ (~10⁻⁶ cm³/sec) is comparable in magnitude to that for $(N_2^+ \cdot N_2)$, $(O_2^+ \cdot O_2)$, and $(NO^+ \cdot NO)$. The substantially different recombination coefficients for monomer ions and "dimer" ions may suggest that the recombination coefficient is related to the complexity of the ions, i.e., increases with the number of internal degrees of freedom of ions.

Finally, by using the $T^{-1/2}$ temperature depen-

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dence predicted theoretically for the direct dissociative process and observed in our experiments for simple ions at temperatures where the molecular ions are principally in their ground vibrational state, a value of $\alpha(H_3^+) \sim 4 \times 10^{-7} \text{ cm}^3/\text{sec}$ is expected at the ionospheric temperature of the outer planets (~100 K) and a value of $\alpha(H_3^+) \sim 2 \times 10^{-6}$ cm^3/sec at the temperature of the interstellar medium (~4 K). If the indirect dissociative process occurs for H_3^+ , an even stronger inverse temperature dependence^{18,23} is to be expected at low temperatures, leading to even larger values of $\alpha(H_3^+)$. Thus those model calculations of the Jovian ionosphere assuming values of electron-ion recombination of the order^{8,9} of $\sim 10^{-8}$ cm³/sec for H₃⁺ and H₅⁺ require major revision. Similarly, calculations of polyatomic-molecule formation in interstellar clouds²⁴ which use room-temperature values of $\alpha(H_3^+)$ should also be modified.

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